

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | | Symbol | Value | Unit |
|---|--------------|------------------------|------------------|-------|------|
| Drain-Source Voltage | | | V _{DSS} | 50 | V |
| Gate-Source Voltage | | | V _{GSS} | ±20 | V |
| Continuous Drain Current (Note 6) V _{GS} = 10V | Steady State | T _A = +25°C | I _D | 5.2 | A |
| | | T _A = +70°C | | 4.2 | |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%) | | | I _{DM} | 25 | A |
| Maximum Continuous Body Diode Forward Current (Note 6) | | | I _S | 1.8 | A |
| Avalanche Current (Note 7) L = 0.1mH | | | I _{AS} | 13 | A |
| Avalanche Energy (Note 7) L = 0.1mH | | | E _{AS} | 8 | mJ |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | Symbol | Value | Unit |
|--|--------------|-----------------------------------|-------------|------|
| Total Power Dissipation (Note 5) (T _A = +25°C) | Steady State | P _D | 1.3 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | | R _{θJA} | 99 | °C/W |
| Total Power Dissipation (Note 6) (T _A = +25°C) | Steady State | P _D | 1.6 | W |
| Thermal Resistance, Junction to Ambient (Note 6) | | R _{θJA} | 77 | °C/W |
| Thermal Resistance, Junction to Case (Note 6) | | R _{θJC} | 13 | |
| Operating and Storage Temperature Range | | T _J , T _{STG} | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|--|---------------------|-----|------|------|------|---|
| OFF CHARACTERISTICS (Note 8) | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 50 | - | - | V | V _{GS} = 0V, I _D = 250µA |
| Zero Gate Voltage Drain Current | I _{DSS} | - | - | 1 | µA | V _{DS} = 50V, V _{GS} = 0V |
| Gate-Source Leakage | I _{GSS} | - | - | ±100 | nA | V _{GS} = ±20V, V _{DS} = 0V |
| ON CHARACTERISTICS (Note 8) | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | 1.0 | - | 3.0 | V | V _{DS} = V _{GS} , I _D = 250µA |
| Static Drain-Source On-Resistance | R _{DS(ON)} | - | 29 | 40 | mΩ | V _{GS} = 10V, I _D = 4.5A |
| | | - | 37 | 60 | | V _{GS} = 4.5V, I _D = 3.5A |
| Diode Forward Voltage | V _{SD} | - | 0.7 | 1.2 | V | V _{GS} = 0V, I _S = 1A |
| DYNAMIC CHARACTERISTICS (Note 9) | | | | | | |
| Input Capacitance | C _{iss} | - | 836 | - | pF | V _{DS} = 30V, V _{GS} = 0V, f = 1.0MHz |
| Output Capacitance | C _{oss} | - | 42 | - | pF | |
| Reverse Transfer Capacitance | C _{rss} | - | 28 | - | pF | |
| Gate Resistance | R _g | - | 2.2 | - | Ω | V _{DS} = 0V, V _{GS} = 0V, f = 1.0MHz |
| Total Gate Charge (V _{GS} = 4.5V) | Q _g | - | 6.5 | - | nC | |
| Total Gate Charge (V _{GS} = 10V) | Q _g | - | 14.5 | - | nC | |
| Gate-Source Charge | Q _{gs} | - | 2.0 | - | nC | |
| Gate-Drain Charge | Q _{gd} | - | 2.3 | - | nC | |
| Turn-On Delay Time | t _{D(ON)} | - | 3.1 | - | ns | V _{DD} = 30V, V _{GS} = 10V, R _L = 6Ω, R _g = 6Ω, I _D = 5A |
| Turn-On Rise Time | t _r | - | 5.0 | - | ns | |
| Turn-Off Delay Time | t _{D(OFF)} | - | 13.4 | - | ns | |
| Turn-Off Fall Time | t _f | - | 3.7 | - | ns | |
| Reverse Recovery Time | t _{RR} | - | 9.4 | - | ns | I _F = 5A, di/dt = 100A/µs |
| Reverse Recovery Charge | Q _{RR} | - | 3.7 | - | nC | |

- Notes:
- Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 - Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 - I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.
 - Short duration pulse test used to minimize self-heating effect.
 - Guaranteed by design. Not subject to product testing.

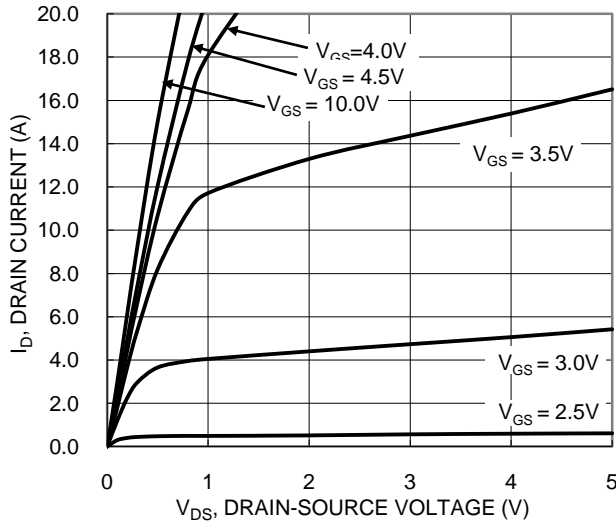


Figure 1. Typical Output Characteristic

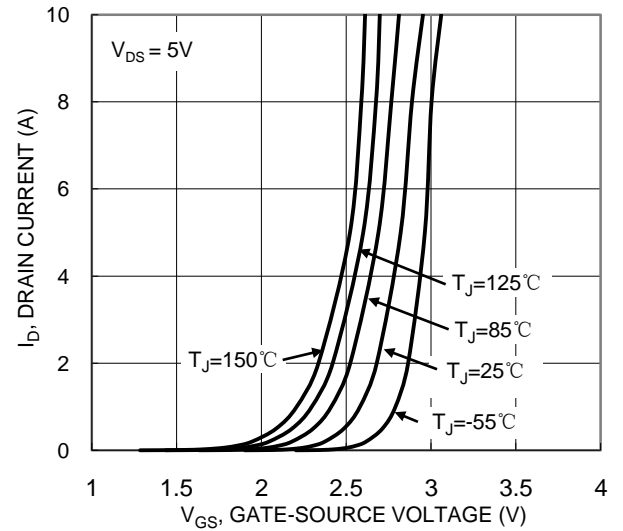


Figure 2. Typical Transfer Characteristic

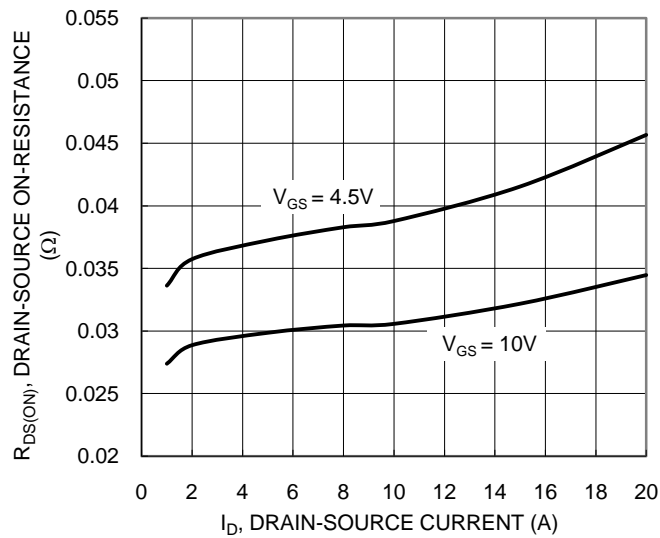


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

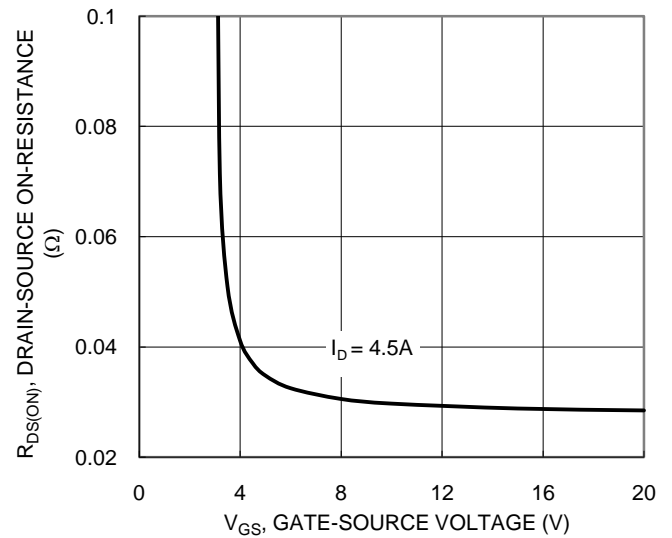


Figure 4. Typical Transfer Characteristic

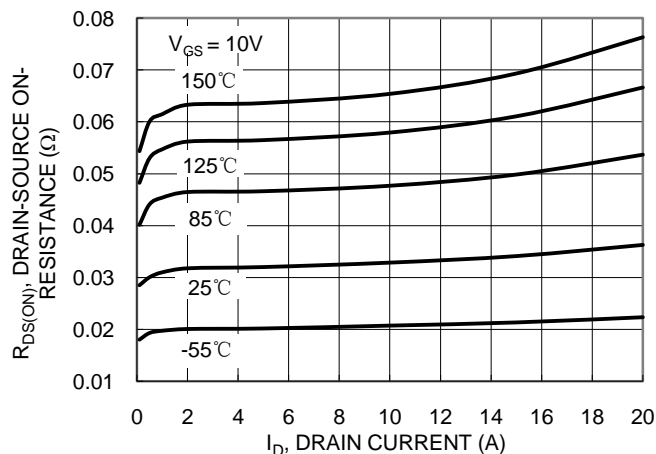


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

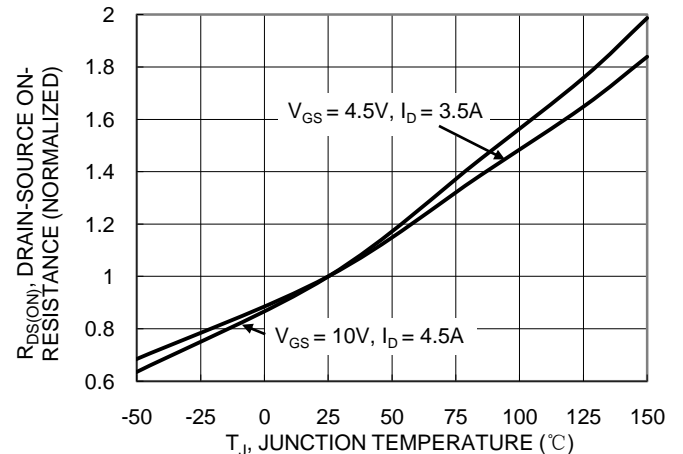
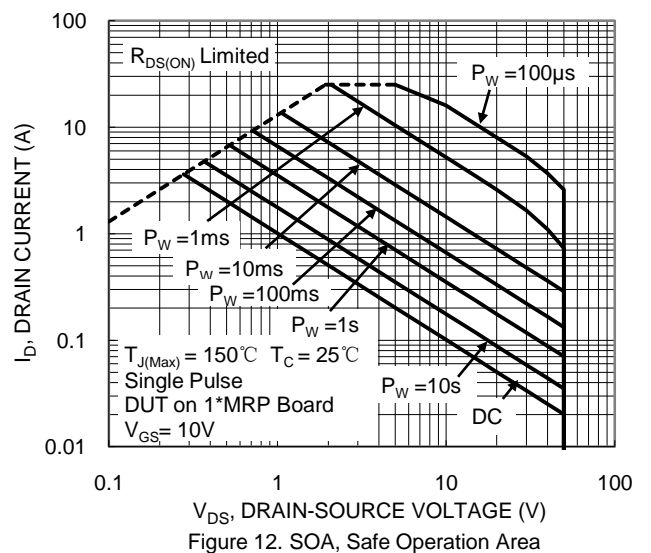
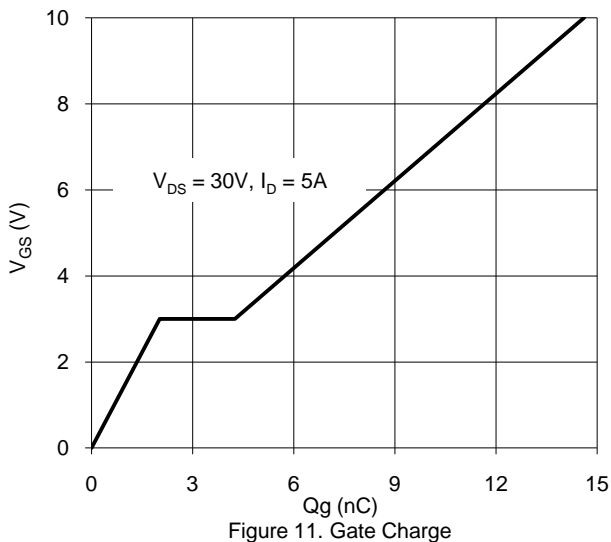
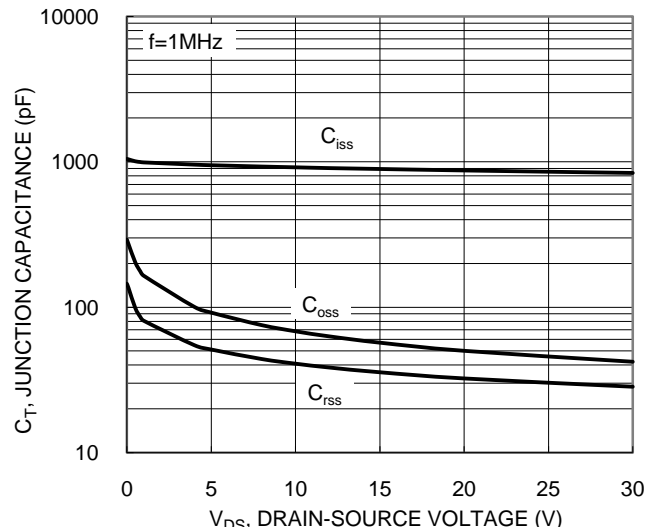
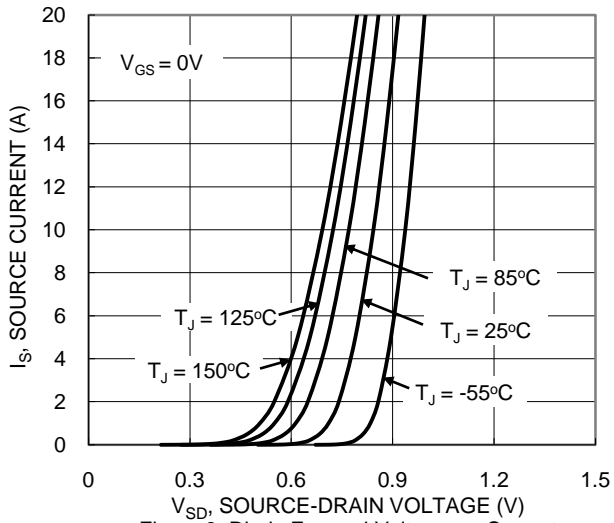
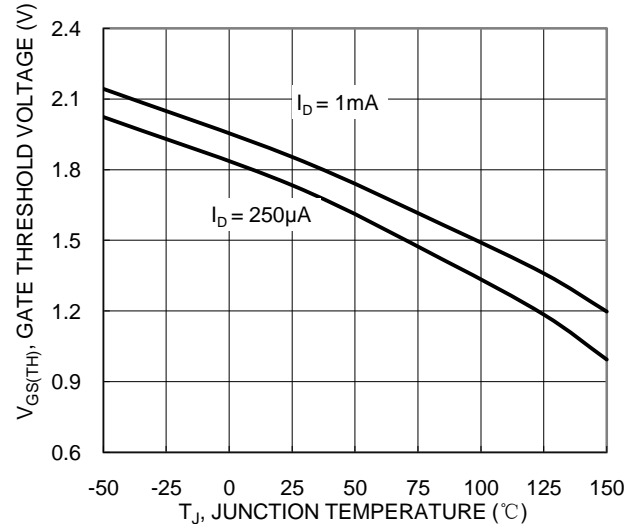
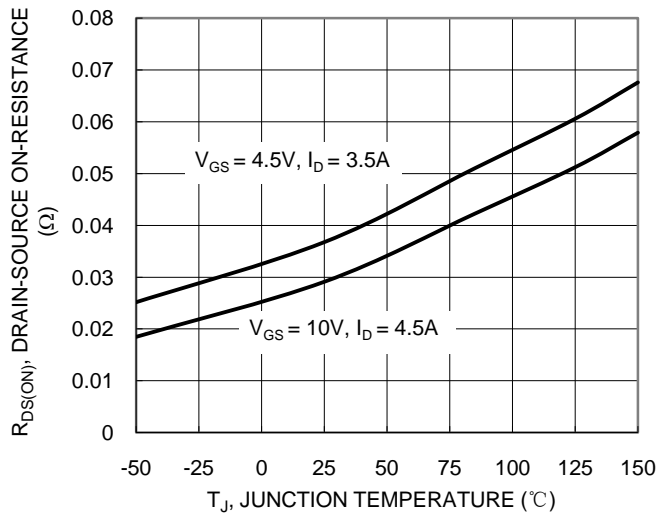


Figure 6. On-Resistance Variation with Junction Temperature



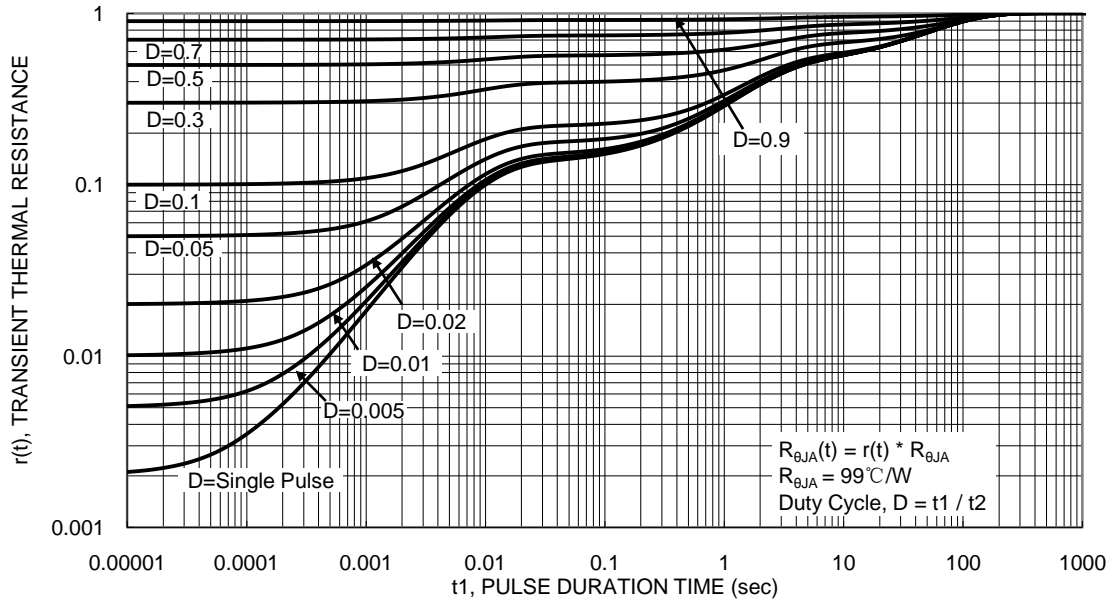
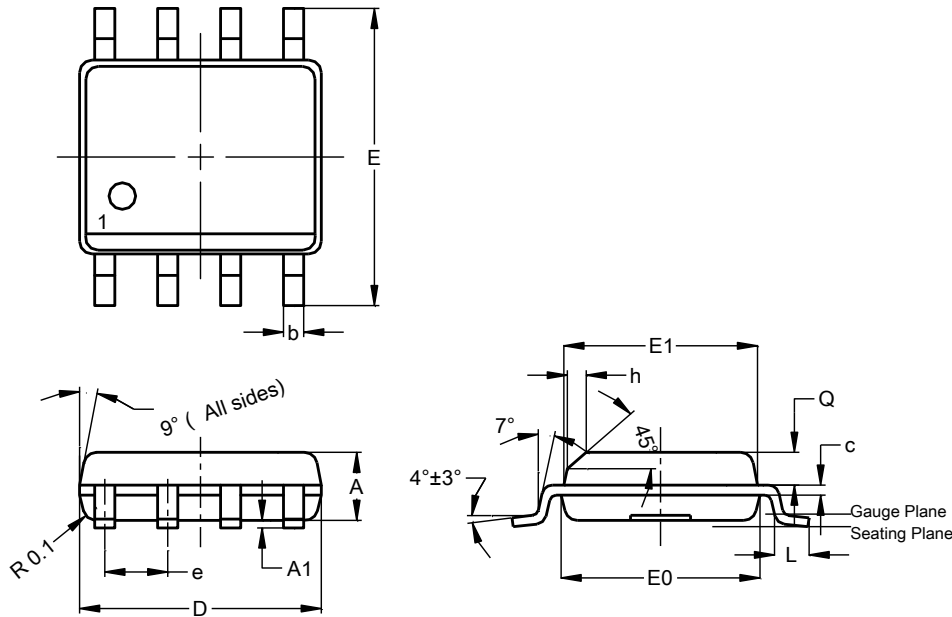


Figure 13. Transient Thermal Resistance

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SO-8

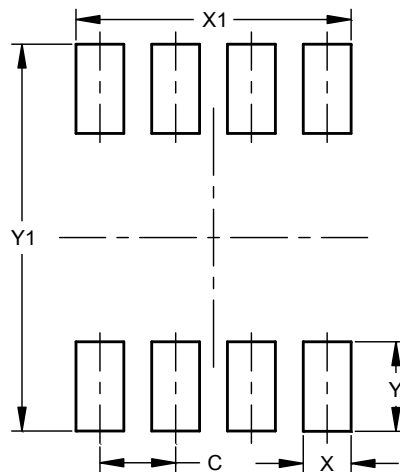


| SO-8 | | | |
|----------------------|------|------|------|
| Dim | Min | Max | Typ |
| A | 1.40 | 1.50 | 1.45 |
| A1 | 0.10 | 0.20 | 0.15 |
| b | 0.30 | 0.50 | 0.40 |
| c | 0.15 | 0.25 | 0.20 |
| D | 4.85 | 4.95 | 4.90 |
| E | 5.90 | 6.10 | 6.00 |
| E1 | 3.80 | 3.90 | 3.85 |
| E0 | 3.85 | 3.95 | 3.90 |
| e | -- | -- | 1.27 |
| h | - | -- | 0.35 |
| L | 0.62 | 0.82 | 0.72 |
| Q | 0.60 | 0.70 | 0.65 |
| All Dimensions in mm | | | |

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SO-8



| Dimensions | Value (in mm) |
|------------|---------------|
| C | 1.27 |
| X | 0.802 |
| X1 | 4.612 |
| Y | 1.505 |
| Y1 | 6.50 |

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